

# Product Standards

PGA26E07BA

Revision. 004

**Panasonic**

PGA26E07BA

Type	GaN-Tr		
Application	For power switching		
Structure	N-channel enhancement mode FET		
Equivalent Circuit	Figure 1		
Out Line	DFN 8X8	Marking	PGA26E07

**A. ABSOLUTE MAXIMUM RATINGS (  $T_j = 25\text{ }^{\circ}\text{C}$  , unless otherwise specified )**

No.	Item	Symbol	Values			Unit	Note
			Min.	Typ.	Max.		
1	Drain-source voltage ( DC ) *1	VDSS	-	-	600	V	
2	Drain-source voltage ( pulse ) *2	VDSP	-	-	750	V	
3	Gate-source voltage ( DC ) *1	VGSS	-10	-	-	V	*VGSS+ is given by IG ratings *See application note
4	Gate current ( DC ) *1	IG	-	-	50	mA	*See application note
5	Gate current ( pulse ) *3,4	IGP	-	-	1.5	A	*See application note
6	Electric gate charge	QGP	-	-	32	nC	*f=200kHz *See application note
7	Drain current ( DC ) ( $T_c = 25\text{ }^{\circ}\text{C}$ ) *1	ID	-	-	31	A	Figure 4
8	Drain reverse current ( DC ) ( $T_c = 25\text{ }^{\circ}\text{C}$ ) *1	IDR	-	-	31	A	
9	Drain current ( pulse ) *5 ( $T_c = 25\text{ }^{\circ}\text{C}$ ) *1	ID pulse	-	-	61	A	Figure 4
10	Drain reverse current ( pulse ) *5 ( $T_c = 25\text{ }^{\circ}\text{C}$ ) *1	IDR pulse	-	-	61	A	
11	Power dissipation ( $T_c = 25\text{ }^{\circ}\text{C}$ )	PD	-	-	125	W	Figure 2
12	Junction temperature	$T_j$	-55	-	150	$^{\circ}\text{C}$	
13	Storage temperature	$T_{stg}$	-55	-	150	$^{\circ}\text{C}$	
14	Drain-source voltage slope	dv/dt	-	-	200	V/ns	

[Special instructions]

\*1 : Please use this product to meet a condition of  $T_j$  within  $150\text{ }^{\circ}\text{C}$ .

\*2 : Spike duty cycle  $D < 0.1$ , spike duration  $< 1\text{ }\mu\text{s}$ , total spike time  $< 1\text{ hour}$ .

\*3 : IGP is defined as  $(V_{cc} - V_{plateau}) / R_{gon}$ , as shown in Figure A.

$V_{plateau}$  is the voltage between Gate and Kelvin Source.

\*4 : Please use this product to meet both a maximum gate current and a maximum gate pulse charge of IGP(1.5A) and Q(32nC) respectively, as shown in Figure H.

\*5 : Pulse width limited by  $T_{jmax}$ .

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Page 2 of 12

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Revision. 004



PGA26E07BA

**B. ELECTRICAL CHARACTERISTICS ( Tj = 25 °C , unless otherwise specified )**

No.	Item	Symbol	Measurement Condition	Min.	Typ.	Max.	Unit
1	Drain cut-off current	IDSS	VDS=600 V, VGS=0 V, Tj=25 °C	-	-	100	μA
			VDS=600 V, VGS=0 V, Tj=150 °C	-	100	-	μA
2	Gate-source leakage current	IGSS	VGS=-3 V VDS=0 V	-1	-	-	μA
3	Gate forward voltage	VGSF	IGS=26.1 mA open drain	2.8	3.5	4.2	V
4	Gate threshold voltage	VTH	VDS=10 V IDS=2.6 mA	0.9	1.2	1.6	V
5	Drain-source on-state resistance	RDS(on)	IGS=26.1 mA, IDS=8A, Tj=25 °C	-	56	70	mΩ
			IGS=26.1 mA, IDS=8 A, Tj=150 °C	-	110	-	mΩ
6	Gate resistance	RG	f=100MHz open drain	-	0.6	-	Ω
7	Transfer conductance	gfs	VDS=8 V IDS=8 A	-	32	-	S
8	Input capacitance	Ciss	VDS=400 V VGS=0 V f=1 MHz	-	405	-	pF
9	Output capacitance	Coss		-	71	-	pF
10	Reverse transfer capacitance	Crss		-	0.4	-	pF
11	Turn-on delay time	td(on)	VDD=400 V IDS=8 A (Figure A, Figure B) Vcc=12 V Rgon=6.2 Ω, Rgoff=4.7 Ω, Rig=680 Ω, Cs=1500 pF	-	3.7	-	ns
12	Rise time	tr		-	5.6	-	ns
13	Turn-off delay time	td(off)		-	5.5	-	ns
14	Fall time	tf		-	2.4	-	ns
15	Effective output capacitance ( energy related )	Co(er)	VDS=0-480 V	-	87	-	pF
16	Effective output capacitance ( time related )	Co(tr)		-	106	-	pF

Revision. 004

**Panasonic**

PGA26E07BA

**C. GATE CHARGE CHARACTERISTICS (  $T_j = 25^\circ\text{C}$ , unless otherwise specified )**

No.	Item	Symbol	Measurement Condition	Min.	Typ.	Max.	Unit
1	Gate charge	Qg	VDD=400 V IDS=8 A (Figure C, Figure D)	-	5.0	-	nC
2	Gate-source charge	Qgs		-	0.9	-	nC
3	Gate-drain charge	Qgd		-	2.6	-	nC
4	Gate plateau voltage	V plateau	VDD=400 V IDS=8 A	-	1.7	-	V

**D. REVERSE CONDUCTING CHARACTERISTICS (  $T_j = 25^\circ\text{C}$ , unless otherwise specified )**

No.	Item	Symbol	Measurement Condition	Min.	Typ.	Max.	Unit
1	Source-drain forward voltage	VSD	VGS=0 V ISD=8 A	-	2.1	-	V
2	Reverse recovery charge	Qrr	VDS=400 V ISD=8 A	-	0	-	nC
3	Reverse recovery time	trr		-	0	-	ns
4	Peak reverse recovery current	Irrm		-	0	-	A
5	Output charge	Qoss		-	45	-	nC

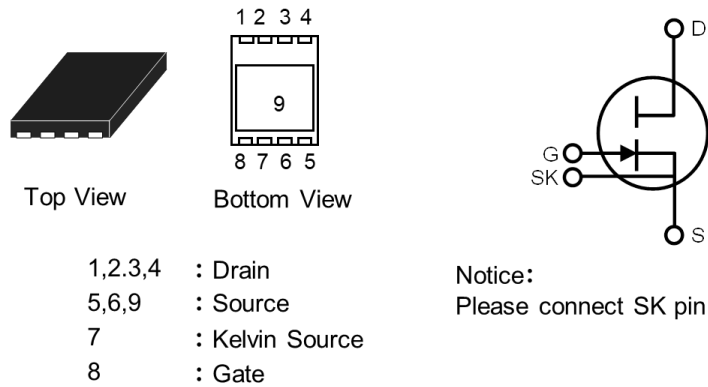
**E. THERMAL RESISTANCE CHARACTERISTICS**

No.	Item	Symbol	Measurement Condition	Min.	Typ.	Max.	Unit
1	Thermal resistance ( junction to case )	Rth(j-c)		-	-	1.0	$^\circ\text{C}/\text{W}$
2	Thermal resistance ( junction to ambient ) *1	Rth(j-a)		-	-	46	$^\circ\text{C}/\text{W}$
3	Reflow soldering temperature	Tsold	reflow MSL3	-	-	260	$^\circ\text{C}$

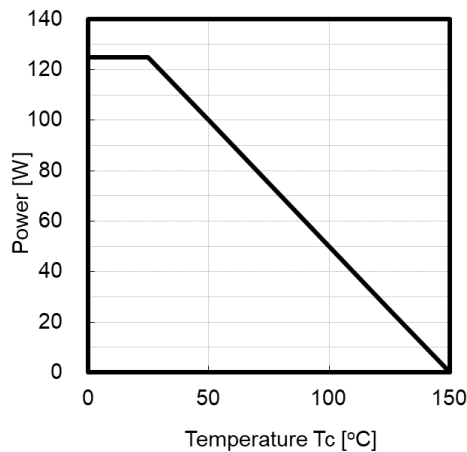
[Notes]

\*1 : Device mounted on four layers epoxy PCB (6.45 cm<sup>2</sup> copper area and 70  $\mu\text{m}$  thickness).

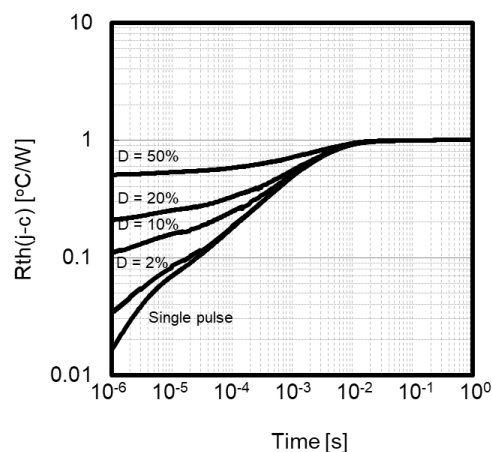
■Equivalent circuit / Electrical characteristics



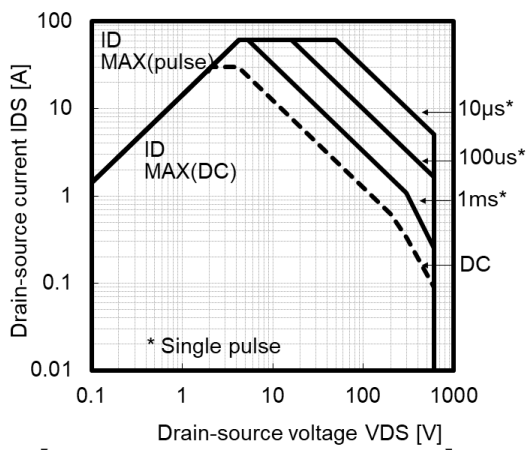
【Figure 1: Pin layout / Equivalent circuit】



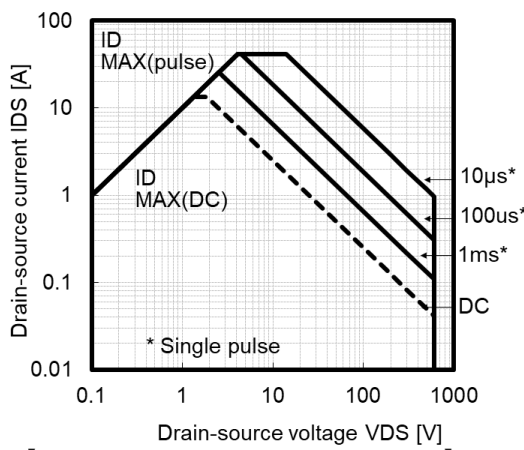
【Figure 2: Max. power dissipation】



【Figure 3: Transient thermal impedance】



【Figure 4: Safe operating area Tc = 25 °C】

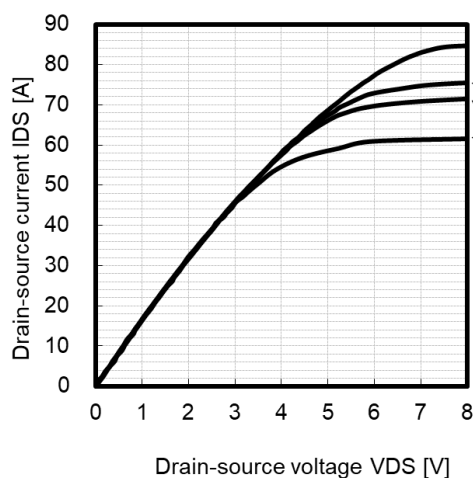


【Figure 5: Safe operating area Tc = 125 °C】

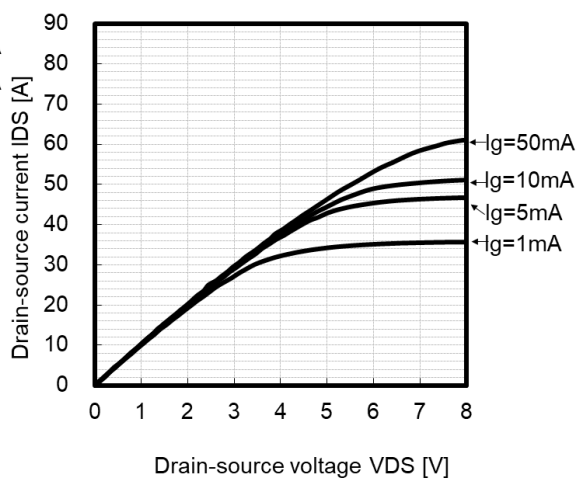
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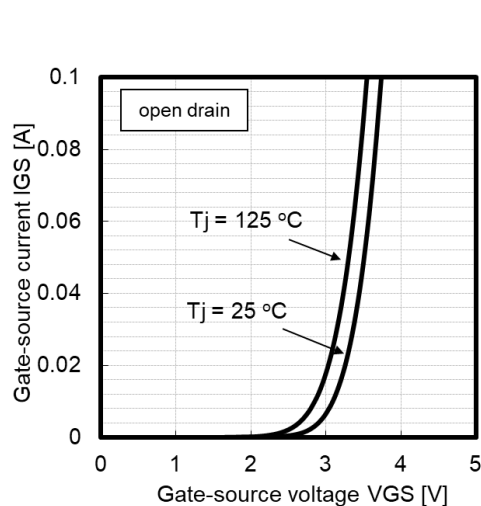
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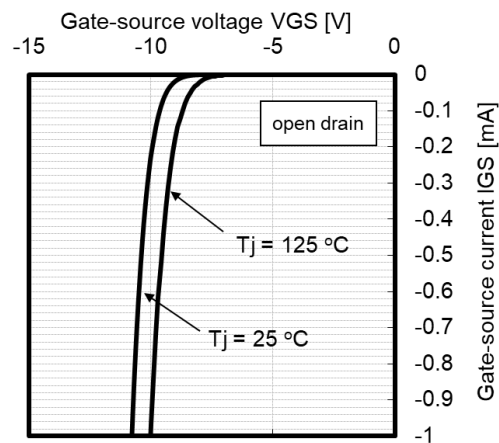
【Figure.6:Output characteristics  $T_c=25^\circ\text{C}$ 】



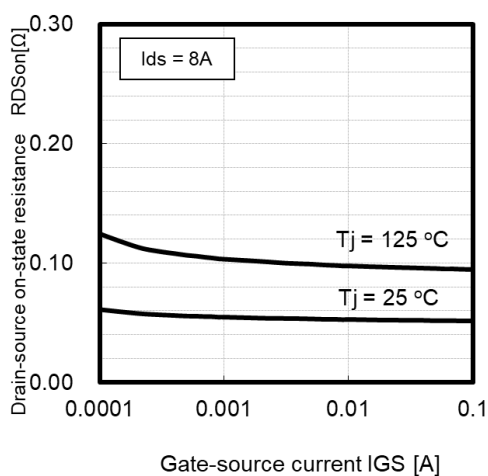
【Figure.7:Output characteristics  $T_c=125^\circ\text{C}$ 】



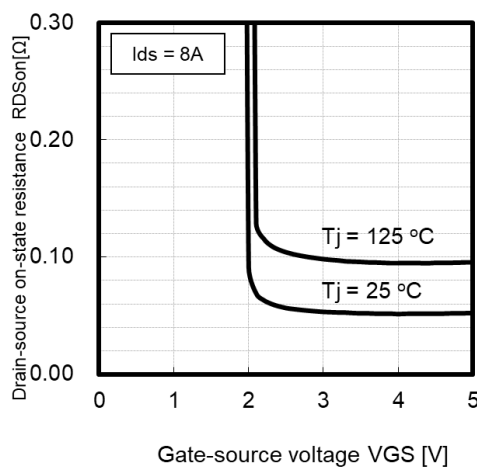
【Figure 8:Gate characteristics】



【Figure.9:Gate characteristics】



【Figure 10:Drain-source on-state resistance】

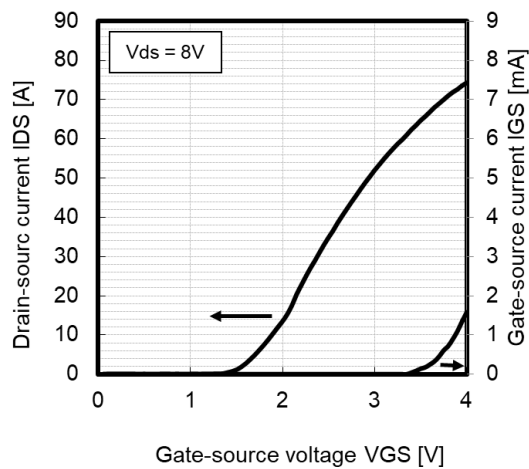


【Figure.11:Drain-source on-state resistance】

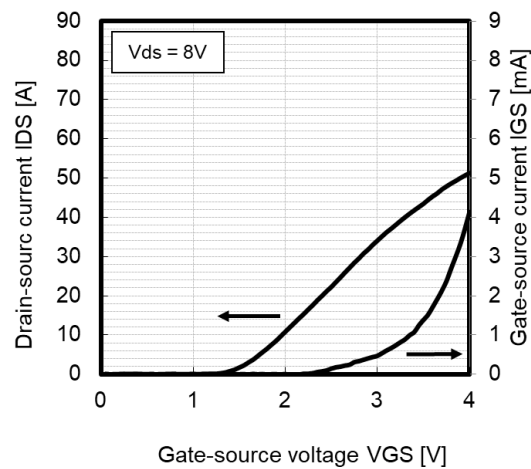
Revision. 004

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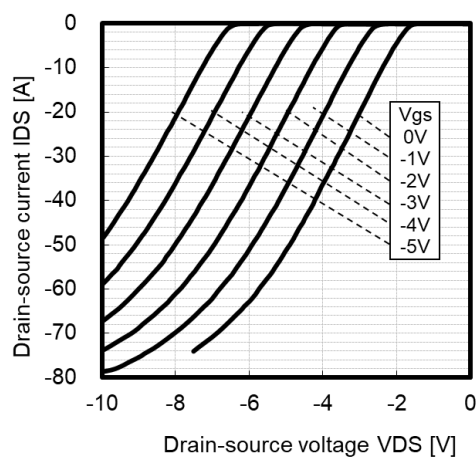
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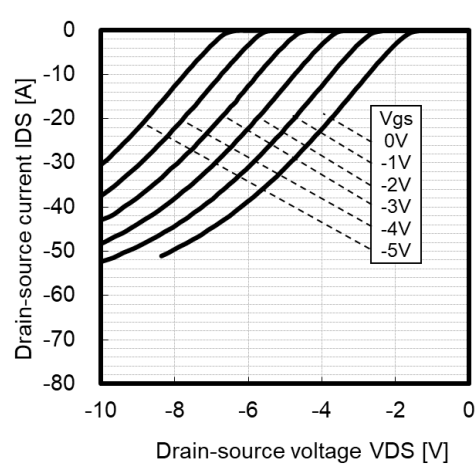
【Figure 12: Transfer characteristics  $T_c=25^{\circ}\text{C}$ 】



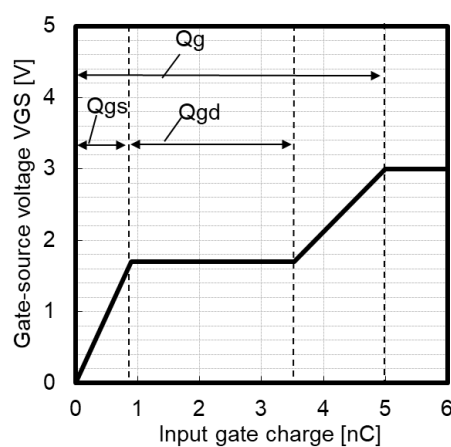
【Figure 13: Transfer characteristics  $T_c=125^{\circ}\text{C}$ 】



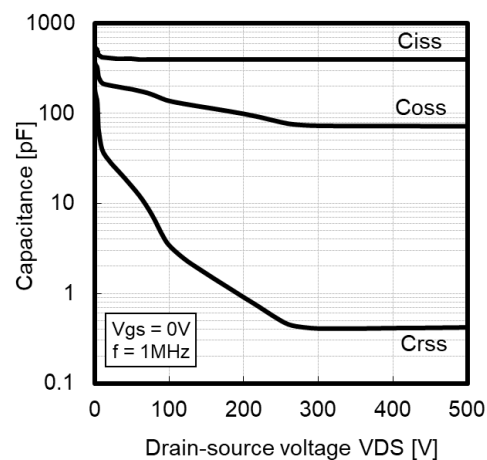
【Figure 14: Reverse channel characteristics ( $T_c=25^{\circ}\text{C}$ )】



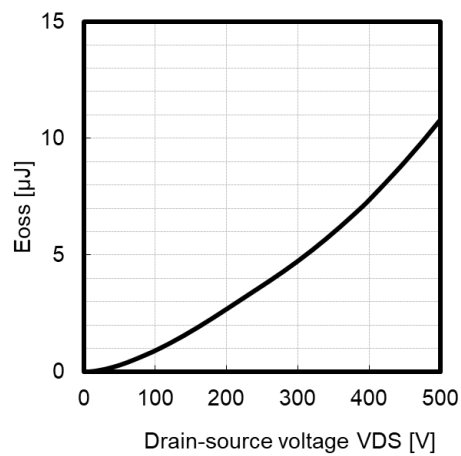
【Figure 15: Reverse channel characteristics ( $T_c=125^{\circ}\text{C}$ )】



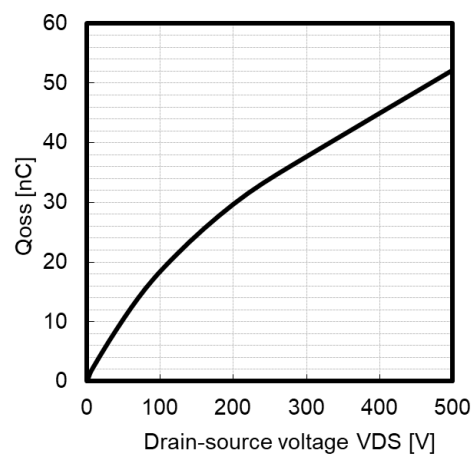
【Figure 16: Gate charge characteristics】



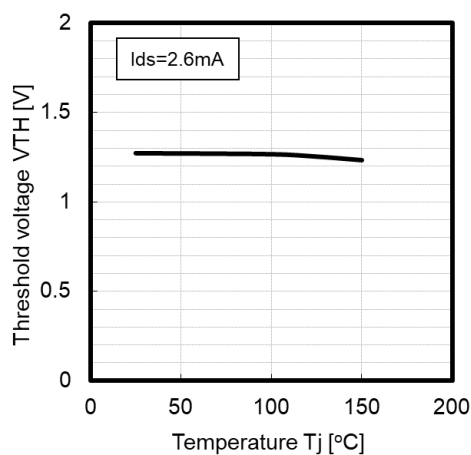
【Figure 17: Capacitance characteristics】



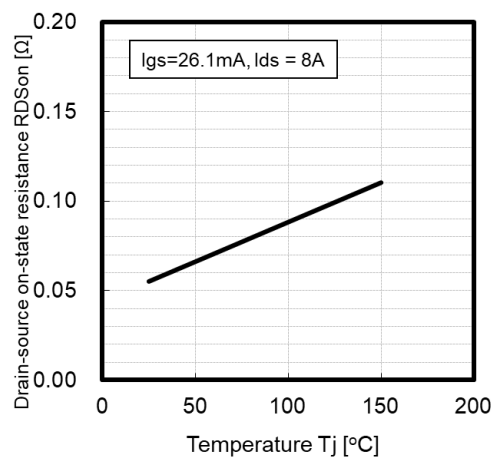
【Figure 18:Output capacitance stored energy】



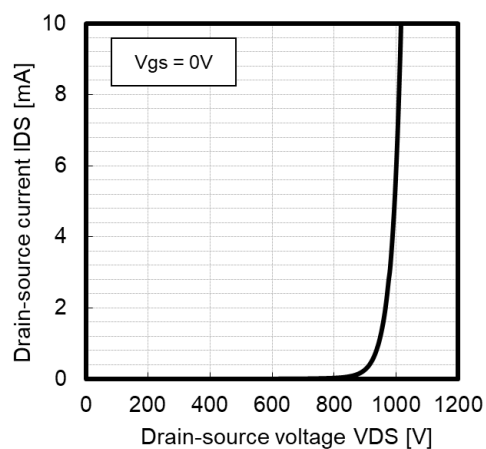
【Figure 19:Output charge】



【Figure 20:Threshold voltage (VTH-Tj)】



【Figure 21:Drain-source on-state resistance(RDS(on)-Tj)】

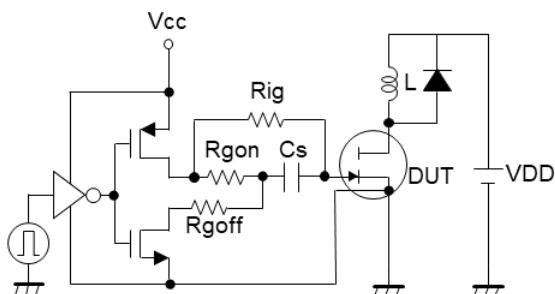


【Figure 22:Drain-Source leakage current (Tc=25°C)】

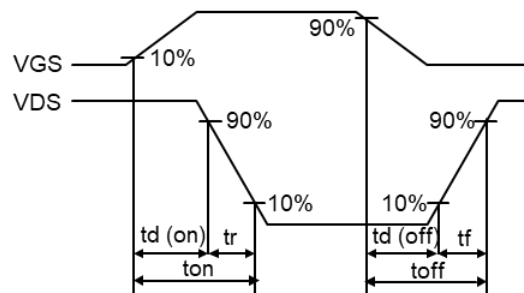
Revision. 004

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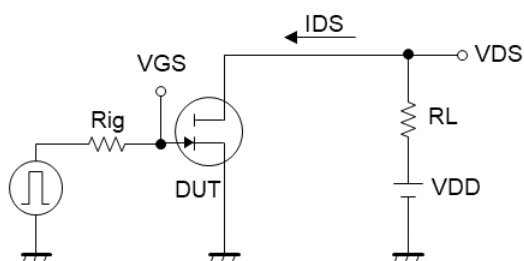
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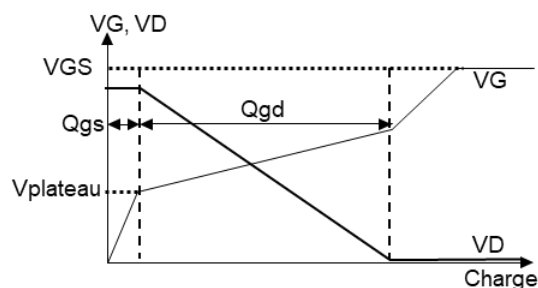
【Figure A : Switching time measurement】



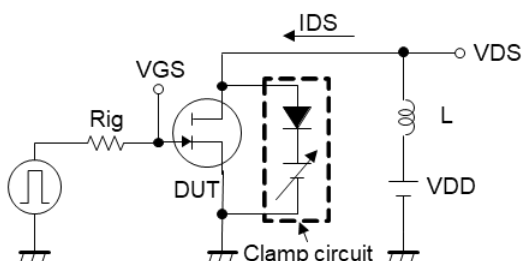
【Figure B : Switching wave form】



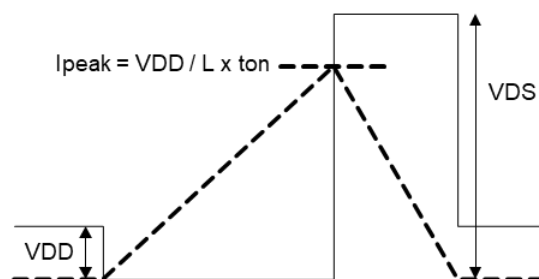
【Figure C : Gate charge measurement】



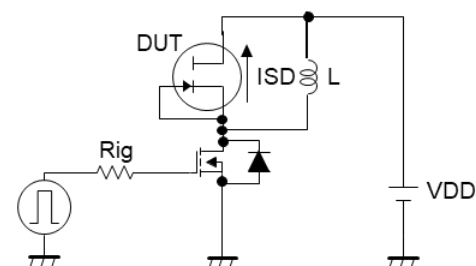
【Figure D : Gate charge wave form】



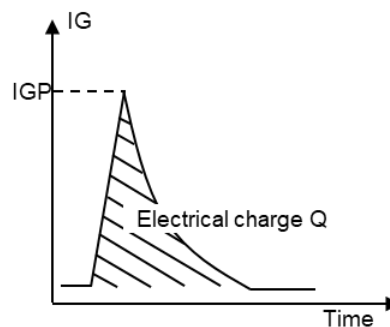
【Figure E : Reverse bias safe operating area  
dv/dt measurement circuit】



【Figure F : Reverse bias safe operating area  
dv/dt wave form】



【Figure G : di/dt measurement circuit】



【Figure H : IGP wave form】

Revision. 004

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PGA26E07BA

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[Precautions for Use]

- 1) The product has risks for break-down or burst or giving off smoke in following conditions. Avoid the following use. Fuse should be added at the input side or connect zener diode between Gate pin and GND, etc as a countermeasure to pass regulatory Safety Standard. Concrete countermeasure could be provided individually. However, customer should make the final judgment.
  - (1) Reverse the Drain pin and gate pin connection to the power supply board.
  - (2) Drain pin short to Kelvin Source pin and Source pin.
  - (3) Drain pin short to Gate pin.
  - (4) Gate pin open.

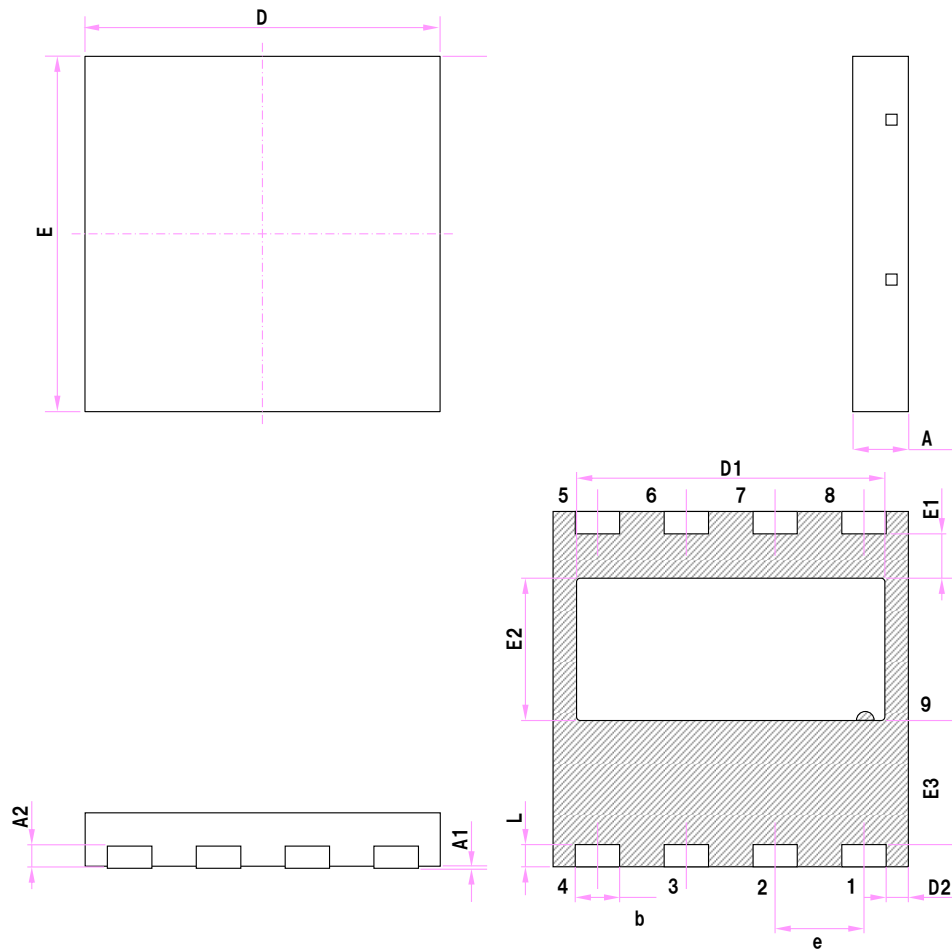
Revision. 004

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## ■ Outline

Unit: mm



SYMBOL	DIMENSION		
	MIN	NOM	MAX
A	1.15	1.25	1.35
A1	0.00	0.02	0.05
A2	0.40	0.50	0.60
b	0.90	1.00	1.10
D	7.90	8.00	8.10
D1	6.84	6.94	7.04
D2	0.40	0.50	0.60
E	7.90	8.00	8.10
E1	0.90	1.00	1.10
E2	3.10	3.20	3.30
E3	2.70	2.80	2.90
e	2.00 B.S.C.		
L	0.40	0.50	0.60

Revision. 004

■ Revision History

Revision No	Date	Description of change
003	2017-01-16	1st edition
004	2019-03-07	Drain current(DC), Power dissipation, Thermal resistance (junction to case), Pin name, Symbol mark, Safe operation area, Output characteristics, Transfer characteristics

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